

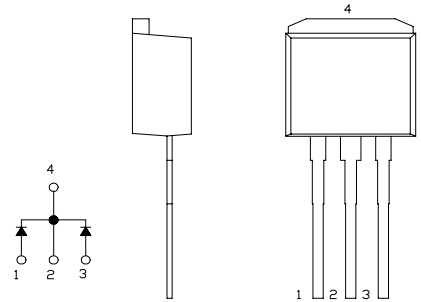
**10A 300V 30ns**
**FRD Type TCU10A30-11A**

OUTLINE DRAWING

For Power Factor Improvement High Frequency Rectification

**FEATURES**

- \* TO-262 Package
- \* Dual Diodes – Cathode Common
- \* Ultra – Fast Recovery
- \* Low Forward Voltage Drop
- \* High Surge Capability


**Maximum Ratings**

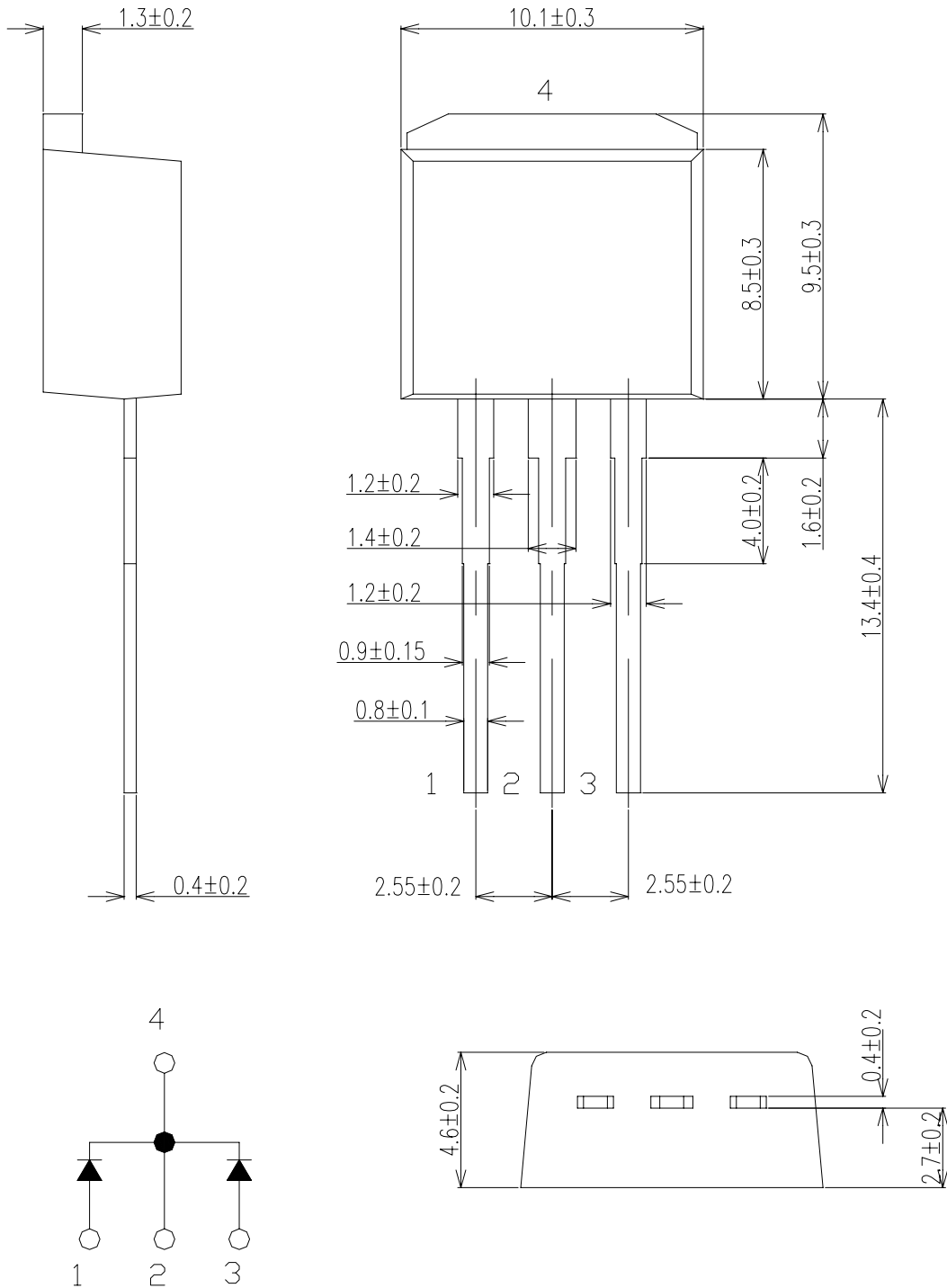
Approx Net Weight:1.45g

Rating	Symbol	TCU10A30-11A		Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	300		V
Average Rectified Output Current	$I_O$	10	$T_c=109^\circ\text{C}$ 50 Hz, Full Sine Wave Resistive Load	A
RMS Forward Current	$I_{F(RMS)}$	11.1		A
Surge Forward Current	$I_{FSM}$	100	50 Hz Full Sine Wave, 1cycle Non-repetitive	A
Operating Junction Temperature Range	$T_{jw}$	- 40 to + 150		$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	- 40 to + 150		$^\circ\text{C}$
Mounting torque		0.5	Recommended value	N•m

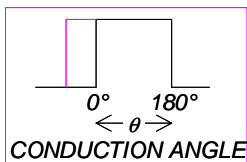
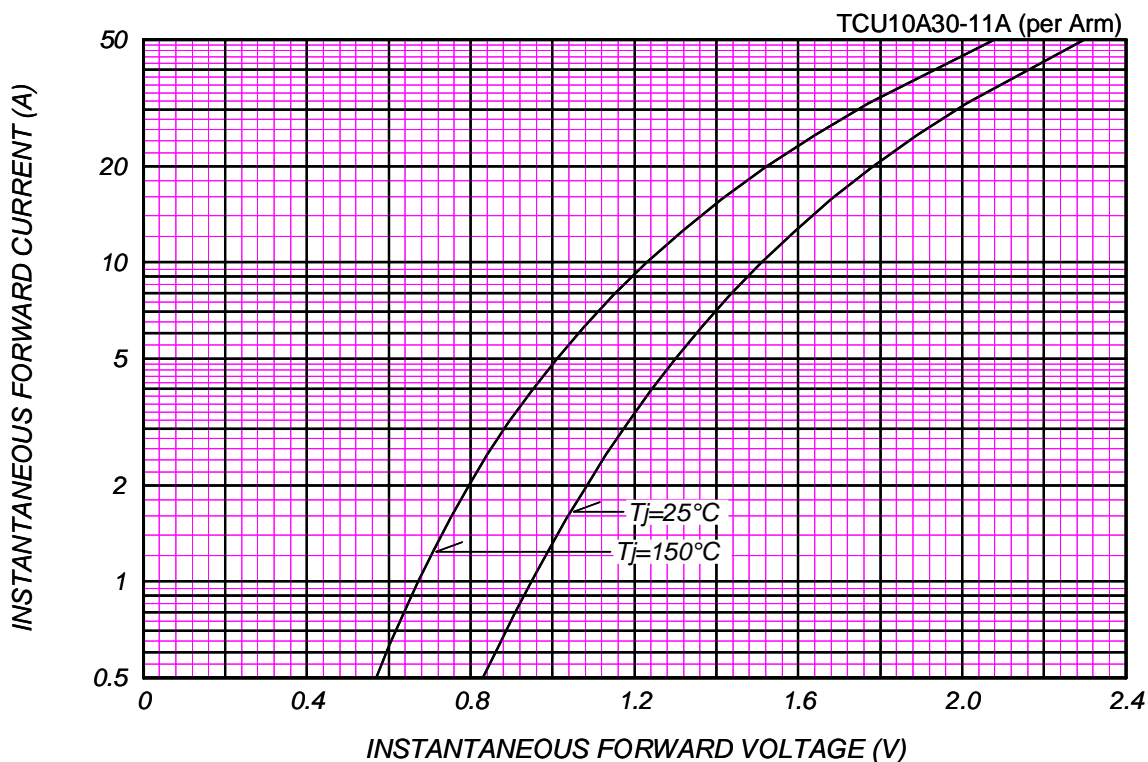
**Electrical • Thermal Characteristics**

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Current	$I_{RM}$	$T_j=25^\circ\text{C}, V_{RM}=V_{RRM}$ per Arm	-	-	25	$\mu\text{A}$
Peak Forward Voltage	$V_{FM}$	$T_j=25^\circ\text{C}, I_{FM}=5\text{A}$ per Arm	-	1.12	1.3	V
Reverse Recovery Time	trr	$I_{FM}=5\text{A}$ , $-di/dt=50\text{A}/\mu\text{s}$ , $T_a=25^\circ\text{C}$	-	19	30	ns
Thermal Resistance	$R_{th(j-c)}$	Junction to Case	-	-	3	$^\circ\text{C}/\text{W}$

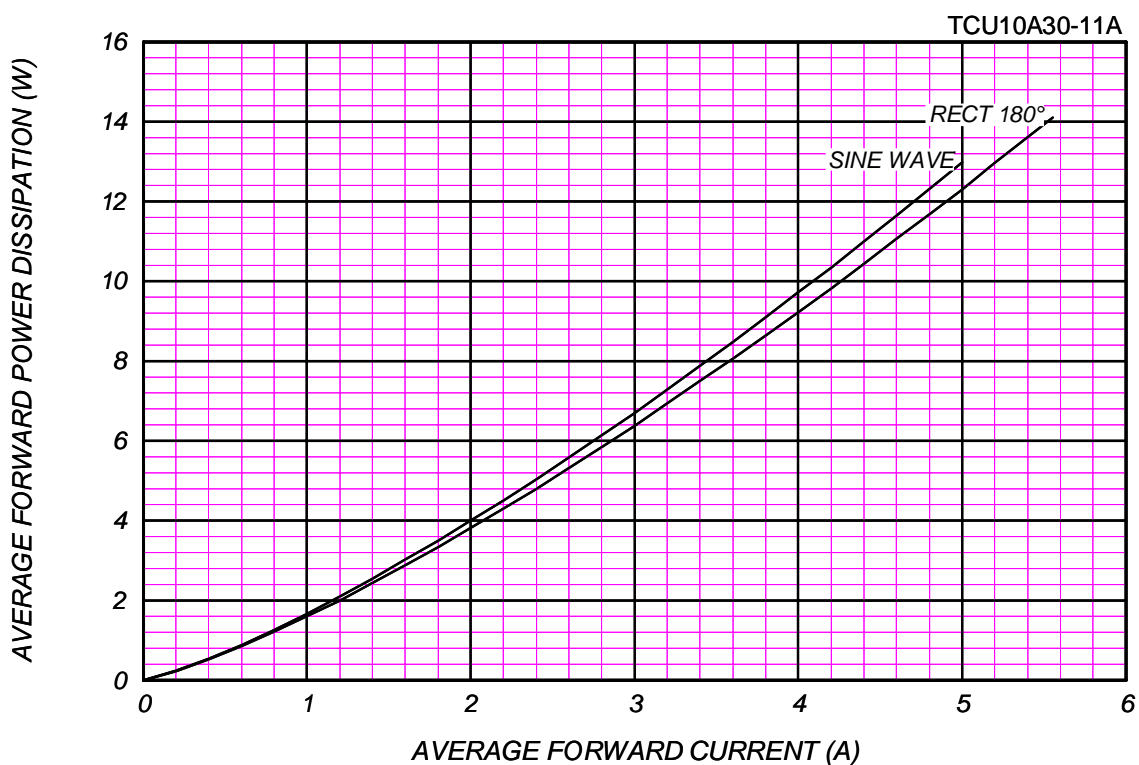
C\_T\_ 11A OUTLINE DRAWING (Dimensions in mm)

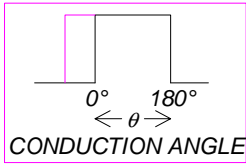


### FORWARD CURRENT VS. VOLTAGE

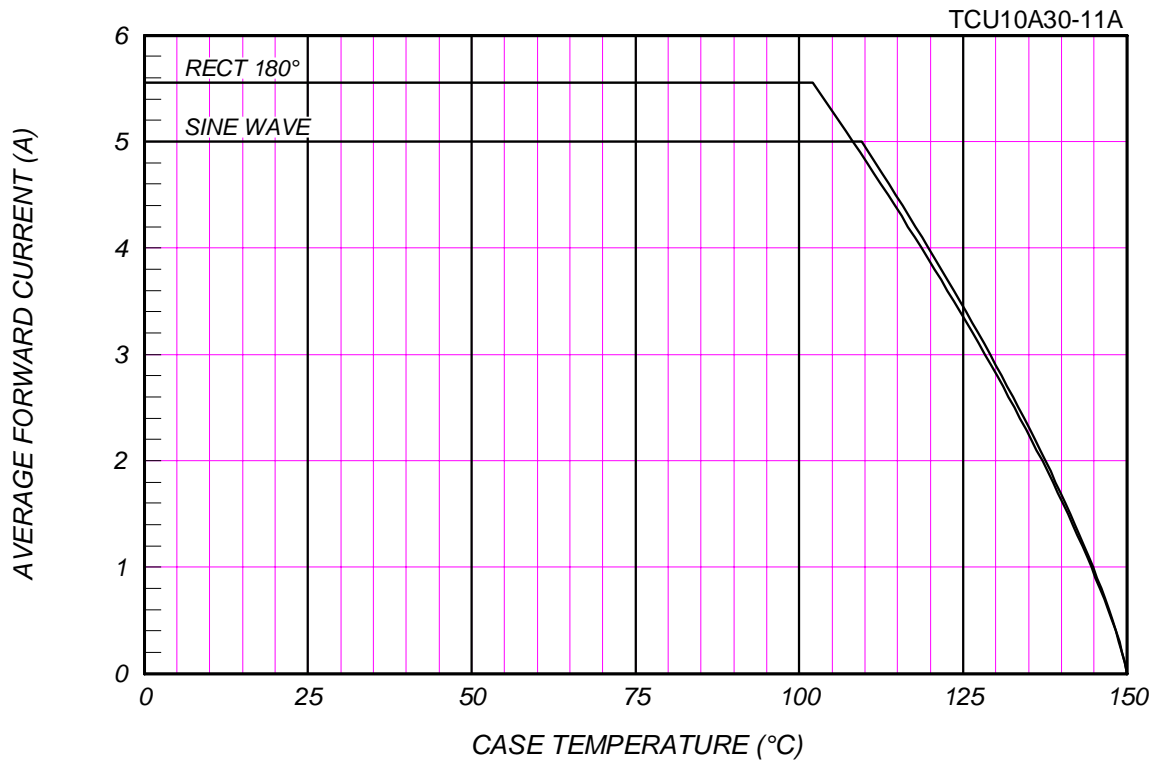


### AVERAGE FORWARD POWER DISSIPATION





### AVERAGE FORWARD CURRENT VS. CASE TEMPERATURE



### SURGE CURRENT RATINGS

f=50Hz, Half Sine Wave, Non-Repetitive, No Load

